7.3 Summary

7.3.1 Summary to 7: MEMS

MEMS are "Micro Electro Mechanical Systems" including also micro optics, micro fluidics and generally meaning micro systems.

- MEMS uses Si substrates and technologies because "it is there and cheap" for the non-electronic part and because electronic components can be integrated on the same chip.
- Examples of high-volume MEMS products are
 - (Pressure) sensors.
 - Accelerometers.
 - Gyros
 - "Beamer" chips (DLP)
- More products are to come; MEMS is an *emerging* and often an enabling technology

Gyros are particular complex **MEMS** sensor products with a huge range of applications.

- There must be a physical principle behind the sensor design; different approaches can be used.
- One approach uses the Coriolis force causing detectable additional vibrations in an oscillator with two degrees of freedom if some rotation is experienced.

Many MEMS devices are either sensors or actuators.

- Looking only at mechanical MEMS, there is a need to couple mechanical movements to electrical signals and vice verse.
- Ways to do this include.
 - Capacitive coupling
 - Piezoelectric and piezoresisitive coupling.
 - Thermal coupling (expansion, resistivity changes).
 - Magnetic coupling.
 - Optical coupling.
- There is no "ideal" coupling; all methods suffer from certain problems.

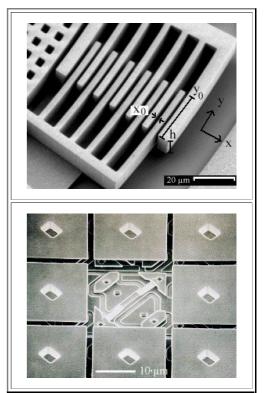
MEMS uses all of "known" **Si** technology and has some specifics of its own.

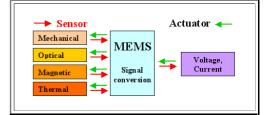
- Making cantilevers and membranes necessitates making "large" cavities.
- Staying absolutely planar and stress-free is essential
- Packaging can be far more demanding than for chips (e.g. transparent tops for OMEMS, keeping defined pressures for > 10 a in gyros).

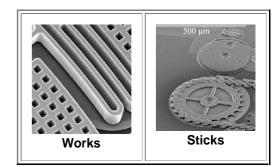
The *bane* of **MEMS** is stiction.

- If you can't lubricate, it will stick sooner or later. Never bring moving parts in contact!
- MEMS design therefore cannot just miniaturize exiting mechanical designs; it must look for new approaches.

MEMS employs some special processes and materials; they are the drivers of progress







- Anisotropic chemical etching
- High-rate plasma etching ("Bosch process")
- Chemical-mechanical polishing
- Sacrificial layers and removal (including chemical etching with "vapors")
- Wafer bonding; in particular for packaging.

Process integration looks simple if compared to an advanced **CMOS** process, but is actually rather involved due to the special processes needed and quality requirements

Making "large" cavities and extremely deep "holes"

Planarization

Free-standing structures

